

# Understanding the structure–property relationships of the ferroelectric to relaxor transition of the $(1 - x)BaTiO_3$ – $(x)BiInO_3$ lead-free piezoelectric system

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# **ABSTRACT**

A structural and electromechanical investigation has been performed on (1 - x)BaTiO<sub>3</sub>–(x)BiInO<sub>3</sub> in the region  $0.03 \le x \le 0.12$ . A gradual structural phase transition has been observed where the structure changes from tetragonal (P4mm) and passes through two regions of coexisting phases: (1) P4mm + R3min the range  $0.03 \le x \le 0.075$  and (2)  $Pm\bar{3}m + R3m$  for  $0.10 \le x \le 0.12$ . The properties also transition from ferroelectric ( $x \le 0.03$ ) to relaxor ferroelectric  $(x \ge 0.05)$  as the dielectric permittivity maximum becomes temperature and frequency dependent. This transition was also confirmed via polarization-electric field measurements as well as strain-electric field measurements. At the critical composition of x = 0.065, a moderate strain of  $\sim 0.104\%$  and an effective piezoelectric coefficient ( $d_{33}^*$ ) of 260 pm/V were observed. The original purpose of this study was to demonstrate the polarization extension mechanism as predicted in the literature, but due to the ferroelectric to relaxor transition, this mechanism was not found to be present in this system. However, this demonstrates that BaTiO<sub>3</sub>-based lead-free ceramics could be modified to obtain enhanced electromechanical properties for actuator applications.

#### Introduction

For the past two decades, there has been tremendous effort put into the search for lead-free piezoelectric materials to replace the industry standard  $Pb(Zr_{1-x}Ti_x)O_3$  (PZT) [1, 2]. PZT remains the material of choice because it shows outstanding properties such

as a high piezoelectric response ( $d_{33} \sim 200$ –600 pC/N) [3], a good electromechanical coupling factor ( $k_p \sim 0.67$ ), and can be easily modified by doping for tailored use in a large number of applications. However, PZT has several major performance disadvantages. It cannot operate above  $\sim 150$  °C, which severely restricts its use in high-temperature applications, and it suffers from stability issues due to

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fatigue. Lead is not currently regulated in electronic devices, but the latest restriction of hazardous substance (RoHS) directive has extended this exemption only three years rather than the usual five years [4]. This change demonstrates that the need for new piezoelectric materials clearly exists, but there is currently no substitute for PZT.

Efforts to find new lead-free materials typically aim to mimic the morphotropic phase boundary (MPB) of PZT, which shows an enhanced piezoelectric effect. PZT's MPB can be derived from a polarization rotation mechanism which results in what can be called a classical MPB, one that lies between two ferroelectric phases with polar crystal structures [5–9]. However, another type of mechanism, called a polarization extension/contraction, exists as described by Damjanovic [8, 10]. A polarization extension occurs between a non-polar phase with a polarization vector of zero, and a polar phase with a non-zero value for the polarization vector. This mechanism can also create an MPB with an enhanced piezoelectric response like that found in a polarization rotation. Calculations have shown that like polarization rotation, a polarization extension occurs when the free energy profile at the boundary between the two phases flattens, allowing the phase to change with ease [10, 11]. The theoretical papers by Damjanovic have hypothesized that materials with a polarization rotation on one end of the MPB and a polarization extension on the other end of the MPB could potentially be very highly performing piezoelectrics. However, these systems have been largely ignored in the literature. A few of the known systems that report a polarization extension include BaTiO<sub>3</sub>-BaSnO<sub>3</sub> [11], AlN-ScN [12, 13], and  $KH_2PO_4$  [14]. It has been predicted that BaTiO<sub>3</sub>-BiInO<sub>3</sub> synthesized by Datta et al. has an MPB derived from a polarization extension mechanism, but the properties had not been measured [10, 15].

BaTiO<sub>3</sub> (BT) is a classical ferroelectric material and crystallizes in the non-centrosymmetric tetragonal space group P4mm where the Ti atom is displaced from the center of the octahedra along [001] [16]. BT has a Curie temperature ( $T_c$ ) of 120 °C where the polarization gives way to the cubic  $Pm\bar{3}m$  structure and has a piezoelectric response ( $d_{33}$ ) of 190 pC/N [17]. As with most pure Bi-based perovskites, BiInO<sub>3</sub> (BI) can only be synthesized at high pressure as it has a small tolerance factor (0.88) [18]. However, using BI in solid

solutions with perovskites that have a higher tolerance factor like PbTiO<sub>3</sub> (PT) (1.019) [19, 20] or BT (1.06) [15] stabilizes this phase at ambient pressures. BI crystallizes in the non-centrosymmetric orthorhombic space group *Pna*2<sub>1</sub>, and it decomposes into two phases upon heating above 600 °C with no structural phase transition recorded, indicating it remains ferroelectric at high temperatures until decomposition [18]. The electromechanical properties of BI have not been reported, but theoretical studies investigating its electronic properties using first principles consider it a promising dielectric material [21] and suggest that it is an excellent candidate for replacing the widely used ferroelectric and piezoelectric PT [22].

The solid solution (1-x)BT–(x)BI is thought to have a compositionally driven polarization extension mechanism as the structure changes from P4mm ( $x \le 0.07$ )  $\rightarrow P4mm + R3m$  ( $x \sim 0.10$ )  $\rightarrow Pm\bar{3}m$  (0.10 < x < 0.25) as the amount of BI increases [10, 15]. This structural change represents a possible MPB in the two phase region with a polarization rotation mechanism on the high BT side and a polarization extension mechanism on the low BT side. In this study, we have investigated the structure and electromechanical properties of the lead-free (1-x)BT–(x)BI system to determine whether this prediction is correct.

# **Experimental**

#### **Synthesis**

Powder samples of (1 - x)BT-(x)BI solid solutions were synthesized in the region  $0.03 \le x \le 0.12$  following a standard solid-state synthesis route. BaCO<sub>3</sub> (Strem Chemicals Inc., 99.9%), TiO<sub>2</sub> (Alfa Aesar, 99.9%), Bi<sub>2</sub>O<sub>3</sub> (Strem Chemicals Inc., 99.999%) and In<sub>2</sub>O<sub>3</sub> (Alfa Aesar, 99.9%) were weighed in stoichiometric ratios where BaCO<sub>3</sub> was placed in a drying oven at 120 °C overnight prior to being weighed. The starting materials were ball milled in a planetary micromill (Pullverisette 7 Classic Line, Fritsch) for 24 h to obtain a homogeneous mixture. During ball milling, each sample was placed in a container with 25 ml of ethanol and eight 10 mm yttria-stabilized zirconia balls, for 45 cycles with each cycle consisting of 15 min forward, 10 min rest, and then 15 min reverse milling direction at a rate of 350 rpm. The resulting powders were calcined in alumina crucibles



at 1000 °C for 8 h. Next, 13-mm pellets were pressed and placed in closed crucibles and sintered at 1200 °C for 5 h buried in sacrificial powder of the same composition to prevent volatilization of bismuth oxide. The cooling and heating rate used was 3 °C/min. Several samples were sent to Galbraith Laboratories Inc for compositional analysis using ICP.

# Pellet processing

For physical properties measurements, pellets with a density ≥95% of the crystallographic value were used as measured by an Archimedes balance. To obtain this high density, after the calcination step, the powders were thoroughly ground in a mortar and pestle and mixed with a 3 wt% polyvinyl butyral (Sigma Aldrich) binder. Then, 13-mm pellets were pressed in a uniaxial press, placed in latex bags and pressed at 210 MPa for 2 min using a cold isostatic press. The sintering conditions were the same as for sample preparation, with the exception of a binder burnout step added at 450 °C for 4 h prior sintering the pellets at 1200 °C for 5–15 h buried in sacrificial powder. Prior to measurement, all pellets were checked by X-ray diffraction (XRD) to ensure that no impurity phases were present.

#### Physical properties measurements

For polarization-electric field (*P–E*) and strain-electric field (S-E) measurements, pellets were polished down into to  $\leq 0.3$  mm thickness with a mirror finish using a semi-automatic polishing machine (LaboPol-5, Struers) with a series of P400, P1200, then P4000 SiC foils (Struers). For electrical contacts, silver conductive paint (SPI supplies #05002-AB) was applied on both sides of the pellets and any deposits on the edges were removed to avoid shorting. P-E and S-E experiments were performed with the pellet submerged in silicon oil at room temperature with frequency of 0.1 Hz using a Radiant high voltage test fixture sample holder attached to a standard ferroelectric test system (Radiant technologies). Measurements of strain as a function of electric field were carried out using an optical displacement sensor (MTI-2100).

High-temperature dielectric permittivity measurements were performed on pellets with thickness ranging from 0.5 to 1 mm. For electrical contacts, high-temperature silver conductive paste (Heraeus

C1000) was applied to the pellets and cured at 750 °C for 2 h. The disks were then placed in a high-temperature measurement cell (NorECS Probostat) and inserted into a tube furnace equipped with a Eurotherm temperature controller. Capacitance and loss were collected against frequency and temperature by using an HP 4192A LF Impedance Analyzer and a LABVIEW program. Measurements were taken over the frequency range of 100 Hz–1 MHz over a temperature range from 25 to 230 °C. The heating and cooling rate used was 2 °C/min.

# Diffraction experiments

XRD data were collected using a Rigaku Miniflex 600 diffractometer with Cu K $\alpha$  radiation ( $\lambda = 1.54056$  Å) to determine phase purity of the synthesized samples. Data were measured over a  $2\theta$  range from  $5^{\circ}$  to  $60^{\circ}$ .

Synchrotron X-ray diffraction (SXRD) data were collected on the beamline 11-BM at the Advanced Photon Source at Argonne National Laboratory [23]. Crushed powders of each composition were diluted with quartz wool to reduce adsorption and were loaded into Kapton capillaries which were spun during the measurement to achieve improved averaging of the powder. SXRD patterns were recorded at room temperature with a wavelength of 0.414219 Å, over 1 h, using standard data collection protocol (30 keV, multi-detector range covering approximately a  $2\theta$  range from  $0.5^{\circ}$  to  $52^{\circ}$ ).

Neutron powder diffraction (NPD) data were collected on the POWGEN diffractometer at Oak Ridge National Laboratory. Approximately 3 g of each powder was loaded into a vanadium can, and NPD data were collected with a central wavelength of 1.066 Å covering a *d*-spacing of 0.276–4.606 Å at room temperature for approximately 2 h.

Combined Rietveld refinements utilizing both the SXRD and NPD data were performed using the software package Topas Academic [24]. For the SXRD data, the Stepheńs model for anisotropic micro-strain broadening was used for modeling the peak profile parameters [25]. The background of both the SXRD and NPD was modeled using 10 coefficients in the Chebyschev model. For a given space group or combination of space groups, the lattice parameters, atomic positions, isotropic atomic displacement parameters, intensity scale factor, profile shape parameters and background were refined. A-site



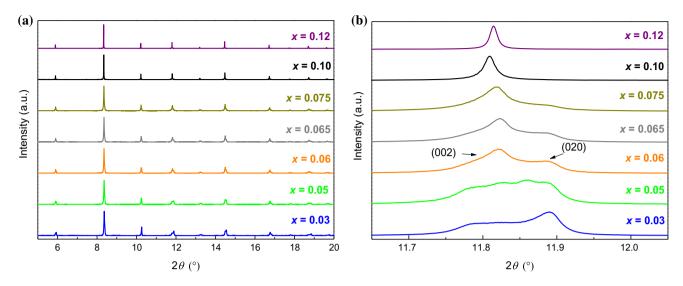


Fig. 1 a Room temperature SXRD patterns for (1 - x)BT - (x)BI ceramics as a function of composition. **b** This shows the modification of (200) reflection upon doping.

atoms (Ba and Bi) were constrained to the origin and equivalent isotropic displacements. The B-site atoms (Ti and In) were also constrained to the same atomic position and isotropic displacements.

#### Results and discussion

#### Structural characterization

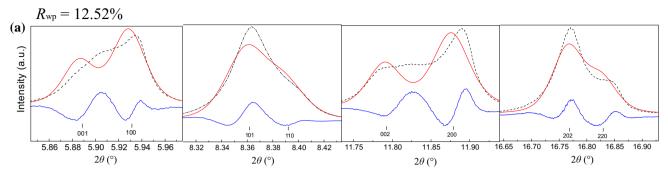
(1 - x)BT - (x)BI ceramics were synthesized successfully in the range  $0.03 \le x \le 0.12$  as determined by XRD. Selected regions of SXRD patterns are shown in Fig. 1a, b. The substitution of BI into BT changes the SXRD data substantially. Thus, the composition x = 0.03 has observable peak splitting for multiple reflections similar to the parent BT (P4mm). In the case of composition x = 0.05, peaks are broad and not well defined. We think this is because it has a coreshell microstructure so the sample is not homogeneous. This issue will be discussed more deeply in the dielectric characterization section. At x = 0.06multiple reflections are still split; however, the relative intensity of them has changed. This is the case of the reflections (002) and (020) as shown in Fig. 1b. For compositions in the range,  $0.065 \le x \le 0.075$ , the reflection (020) decreases the intensity as x increases as shown in Fig. 1b. Finally, at  $x \ge 0.10$ , a single peak is observed suggesting an increase in symmetry.

Previous structural characterization has been carried out by Datta et al. [15] on the system (1 - x)BT - (x)BI, where x is 0.03–0.25. Based on Rietveld

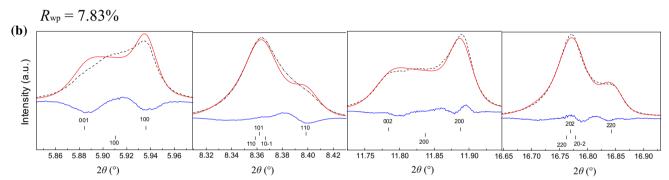
analysis, they determined that compositions in the range  $0.03 \le x \le 0.07$  crystallize in *P4mm* and when  $x \ge 0.15$  the structure is cubic with space group  $Pm\bar{3}m$ . Interestingly, they reported that composition x = 0.10 acts as a bridge between the tetragonal and cubic structures, where its structure was determine to be multi-phase with P4mm (~18 wt%) + R3m( $\sim$ 82 wt%) space groups. In our structural study, initially a Rietveld refinement was performed for the composition x = 0.03 using the structural parameters previously reported in P4mm by Datta et al. However, a good fit was not achieved giving a goodness of fit parameter  $R_{\rm wp}$  of 12.52% (Fig. 2a). Upon careful inspection of the SXRD data, it was observed that reflections are less split compared to the previous published data on this system at x = 0.03 and there were clearly peaks in the pattern that were not fit using the single-phase model [15]. Therefore, a multi-Rietveld refinement for x = 0.03phase P4mm + R3m was attempted using as starting model the structural parameters previously published for x = 0.10. In this case, a better fit was achieved with an  $R_{\rm wp} = 7.83\%$  where the unindexed peaks from the P4mm model are now fit as Fig. 2b shows. The combination of space groups  $P4mm + Pm\bar{3}m$  was also tried for x = 0.03. However, the displacement parameters of the B-site for the cubic component, refined to negative values. Datta et al. came to same conclusion for x = 0.10, as the isotropic displacement parameters of all atoms for the cubic structure were refined to negative and large numbers [15]. Thus,







#### P4mm + R3m

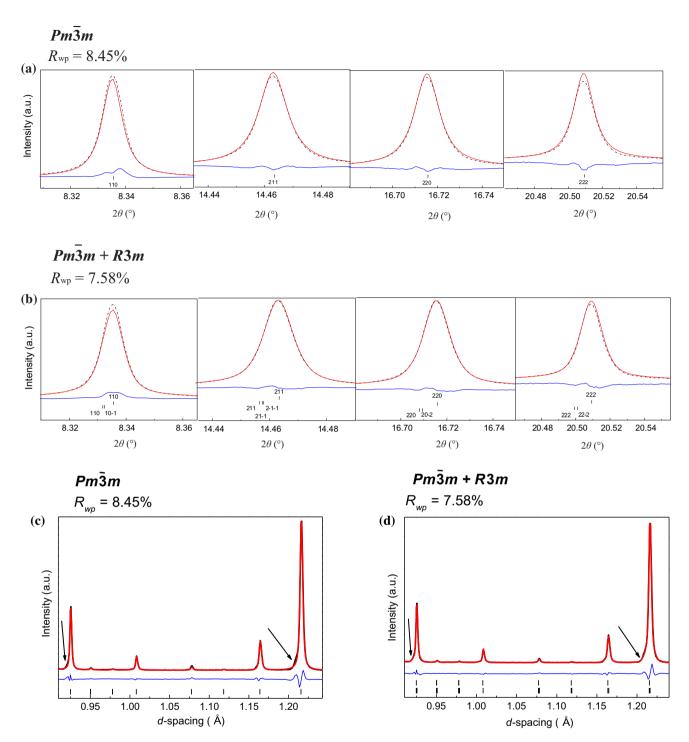


**Fig. 2** The fits of selected reflections in Rietveld refinements of x = 0.03 using **a** single-phase *P4mm* and **b** multi-phase *P4mm* and *R3m* with the upper *tic marks* from *P4mm* and the lower *tic* 

marks from R3m for SXRD data. The black circles represent the observed data; the red solid line represents the model, while the blue difference curve is below.

replacing the cubic  $Pm\bar{3}m$  by a rhombohedral model R3m, which has more degrees of freedom than Pm3m resulted in positive displacement parameters for all atoms. We therefore consider the multi-phase Rietveld refinement for x = 0.03 in P4mm + R3m to be a reasonable approximation to the structures observed by diffraction. Selected reflections refined using the two different models are shown in Fig. 2. This result clearly demonstrates that a phase combination model in P4mm + R3m (Fig. 2b) describes the measured diffraction pattern better than a single-phase refinement (Fig. 2a). For this x = 0.03 composition, the phase fraction can be modeled at 50 wt% P4mm and 50 wt% R3m with the amount of the R3m phase increasing up to the x = 0.075 composition. This increase in the amount of R3m phase corresponds with an increase in Bi<sup>3+</sup> cations on the A-site makes sense in context with the transition to relaxor ferroelectric properties (discussed below) along with the tendency of ambient pressure Bi-based perovskites to displace along [111]<sub>p</sub> as in Bi(Fe<sub>2/8</sub>Ti<sub>3/</sub>  $_{8}$ Mg<sub>2/8</sub>)O<sub>3</sub> [26] and BiFeO<sub>3</sub> [27]. When  $x \ge 0.10$ , an increase in symmetry is observed in the SXRD pattern (Fig. 1b). For x = 0.12, a refinement in  $Pm\bar{3}m$ was attempted as described by Datta et al. for the compositions with high symmetry obtaining an  $R_{\rm wp} = 8.45\%$ . However, the cubic space group  $Pm\bar{3}m$  did not account well for the intensities of some reflections in the SXRD data as Fig. 3a shows. Furthermore, the cubic space group could not model some shoulders in the NPD data, Fig. 3c. A singlephase rhombohedral space group R3m fit was also attempted and negative values for the isotropic displacement parameters for the B-site were obtained. Therefore, a multi-phase Rietveld refinement in  $Pm\bar{3}m + R3m$  was performed and a satisfactory fit was achieved with an  $R_{\rm wp} = 7.58\%$ . As Fig. 3b, d shows, this multi-phase refinement better models the intensities and the shoulders in the NPD data. Thus, the structure of compositions in the range  $0.10 \le x \le 0.12$  was solved as a mixture of  $Pm\bar{3}m + R\bar{3}m$  with the amount of  $Pm\bar{3}m$  increasing with x content as expected from  $\sim 21$ wt%.  $Pm\bar{3}m + \sim 79 \text{ wt}\%$ R3mto  $\sim$  26 wt%  $+ \sim 74$  wt% R3m for x = 0.10 and 0.12, respectively. Final refined values of each composition are listed in





**Fig. 3** The fits of selected reflections in Rietveld refinements of x = 0.12 using **a**–**c** single-phase  $Pm\bar{3}m$  and **b**–**d** multi-phase  $Pm\bar{3}m$  and R3m with the upper *tic marks* from  $Pm\bar{3}m$  and the lower *tic marks* from R3m. The SXRD data is on top and NPD

Table 1. Additional refined values (atomic positions and isotropic displacement parameters) are listed in Table S1 (supplementary information).

data on the bottom. The *black circles* represent the observed data; the *red solid line* represents the model, while the *blue* difference *curve* is below.

These structural determinations differ from Datta et al.'s which found the structure to be single-phase P4mm when x < 0.10, multi-phase P4mm + R3m at



**Table 1** Structural parameters from the combined Rietveld refinement of (1 - x)BT - (x)BI ceramics using APS and POWGEN data

Composition $(x)$	Space group	Phase (wt%)	Lattice parameters (Å) and angles (°)	Quality of fit
0.03	P4mm	50	a = 4.0009 (6)	$R_{\rm wp} = 7.83\%$
			c = 4.0346 (9)	•
	R3m	50	a = 4.019(1)	
			$\alpha = 89.84 (4)$	
0.05	P4mm	38	a = 4.0039 (4)	$R_{\rm wp} = 8.91\%$
	R3m	62	c = 4.035(1)	•
			a = 4.021 (1)	
			$\alpha = 89.89 (5)$	
0.06	P4mm	28	a = 4.0023 (9)	$R_{\rm wp} = 7.53\%$
			c = 4.036(1)	
	R3m	72	a = 4.0226 (4)	
			$\alpha = 89.957(6)$	
0.065	P4mm	20	a = 4.002(1)	$R_{\rm wp} = 7.72\%$
			c = 4.039(2)	•
	R3m	80	a = 4.0230(3)	
			$\alpha = 89.99 (9)$	
0.075	P4mm	14	a = 4.0019(5)	$R_{\rm wp} = 8.11\%$
			c = 4.041 (2)	
	R3m	86	a = 4.0243(2)	
			$\alpha = 89.97 (4)$	
0.10	$Pm\bar{3}m$	21	a = 4.037(2)	$R_{\rm wp} = 10.31\%$
	R3m	79	a = 4.02722 (9)	
			$\alpha = 89.99 (5)$	
0.12	Pm3̄m	26	a = 4.031 (1)	$R_{\rm wp} = 7.58\%$
	R3m	74	a = 4.03189 (4)	<b>"P</b>
	2.0	, ·	$\alpha = 89.952 (9)$	

x = 0.10 and single-phase  $Pm\bar{3}m$  when x > 0.10. The synthesis in the Datta paper reported pellets were sintered for structural analysis at 1400 °C for 4 h, with no mention of a sacrificial powder being used. Our attempts to replicate this synthesis resulted in the inability to achieve reproducible physical properties on different pellets of the same composition from the same batch. Attempts were made to lower the sintering temperature to 1300 °C for 1–2 h buried in sacrificial powder, which also resulted in the inability to reproduce physical property measurements. This inconsistency in properties measureindicates that the higher temperatures likely lead to volatility of the bismuth cations. Therefore, we had to decrease the sintering temperature to 1200 °C which had an impact on the structure of the entire series of compositions. Although obtaining accurate compositional analysis of Bi-based compounds is notoriously difficult, ICP measurements were performed on the x = 0.03 composition to determine whether this theory could be accurate. The expected Ba/Bi molar ratio is 0.97:0.03. The ratio determined by ICP measurements using the compound sintered according to the Datta paper was 0.97:0.026, while the compound sintered at lower temperatures was 0.97:0.029. While the difference is small, it does show Bi<sup>3+</sup> volatilization could be occurring when sintering at the higher temperatures reported by Datta.

#### Dielectric characterization

Relative permittivity for (1 - x)BT–(x)BI ceramics across the full range of compositions,  $0.03 \le x \le 0.12$ , as a function of temperature are shown in Fig. 4a. None of the compositions exhibit a sharp phase transition typical of a ferroelectric material like in the parent compound BT. In this system, the peaks become broader with content of x (Fig. 4a, d), where a broad frequency dependent maximum permittivity is



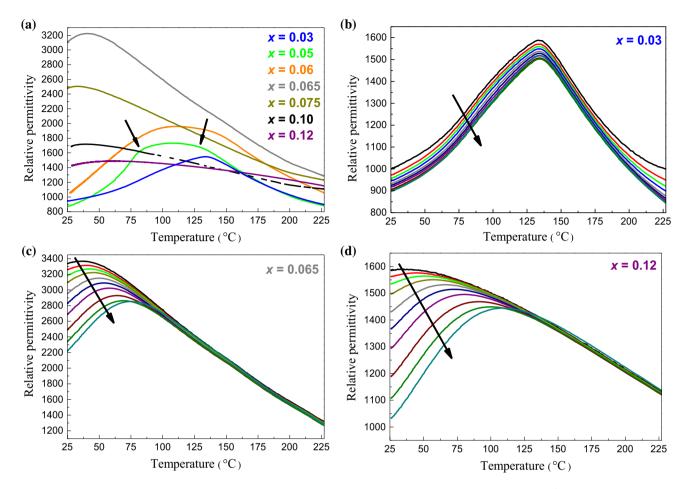


Fig. 4 Temperature dependence of relative permittivity of: a (1 - x)BT–(x)BI ceramics measured at 10 kHz. b x = 0.03. c x = 0.065 and d x = 0.12 at different frequencies from 1 kHZ to 1 MHz.

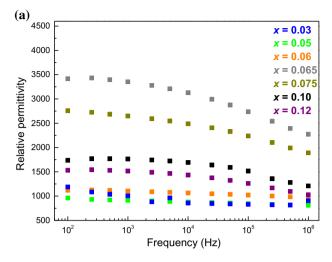
observed, indicating a transition to a weakly coupled relaxor material [28, 29]. This behavior has been observed for other related systems such as: BaTiO<sub>3</sub>-BiScO<sub>3</sub> (BT-BS) [28], BaTiO<sub>3</sub>-Bi(Zn<sub>0.5</sub>Ti<sub>0.5</sub>)O<sub>3</sub> (BT-BZT) [30, 31], and BaTiO<sub>3</sub>-BiAlO<sub>3</sub> (BT-BA) [32]. In this BT-BI system, the temperature of maximum permittivity ( $T_{\text{max}}$ ) decreases as more BI is added into the solid solution. It might be assumed that the  $T_{\text{max}}$ should have increased in relation to BT because the  $T_c$ for BT is  $\sim 120$  °C [17], while the  $T_c$  of BI is >600 °C [18]. However, this trend of a ferroelectric-relaxor ferroelectric transition with  $T_{\text{max}}$  decreasing has also been observed in the similar system BT-BA [32]. The reason for the trends in  $T_{\text{max}}$  is unclear in the literature, and further investigations are necessary to understand the nature of the change as a function of composition. In contrast to these BT-based materials, solid solutions of PbTiO<sub>3</sub> with BiAlO<sub>3</sub> (PT-BA) [33], BiInO<sub>3</sub> (PT-BI) [20], and BiScO<sub>3</sub> (PT-BS) [19, 34, 35] maintain ferroelectricity over much

composition ranges sometimes through a phase transition where the PT-BS materials have an MPB.

For the x = 0.05 composition, two permittivity peaks are observed as indicated by black arrows in Fig. 4a at about 90 and 125 °C. This effect could be from a local core—shell microstructures resulting from a difficulty to homogenize during sintering and is commonly found at low substitution percentages in these types of systems. This phenomenon has been observed in the system (1 - x)BT-xBS by Ogihara et al. [28] and 0.98BT-0.02BA by Zheng et al. [32]. In BT-BS when x = 0.05, two clear permittivity peaks appear for ceramics sintered for 1 h. Based on TEM and elemental analysis, they claim that the cores of the grains are rich in BT and responsible for the higher temperature peak. In contrast, the shell is rich in BS and accounts for the lower temperature peak.

Room temperature dielectric measurements of both relative permittivity and loss show frequency dispersion (Fig. 5a, b respectively). The data show that





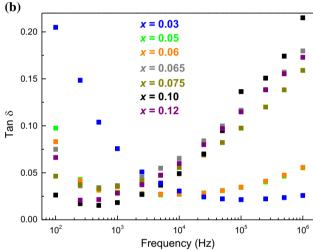


Fig. 5 a Dielectric constant and b loss tangent as a function of frequency at room temperature for (1 - x)BT - (x)BI ceramics.

the permittivity is the highest for x = 0.065 at the whole frequency range (Fig. 5a). The maximum relative permittivity value at 10 kHz for x = 0.065 is

3220, which is much lower than that of ferroelectric BT (25000) [32] but similar to the permittivity found upon the addition of BA in 0.95BT-0.05BA (3500) which also becomes relaxor-like [32]. The loss also shows frequency dispersion where a dielectric relaxation is present that shifts as a function of frequency (Fig. 5b). The x = 0.03 sample has the highest loss at low frequencies (0.2048 at 100 Hz), but the lowest loss at higher frequencies (0.0258 at 1 MHz) where the x = 0.10 and x = 0.12 compositions have the lowest loss at low frequencies (0.0263 and 0.0663, respectively, at 100 Hz) and high loss at higher frequencies (0.215 and 0.1729, respectively, at 1 MHz). The frequency dispersion is also evident by examining  $\Delta T_{\text{max}}$  (the difference between  $T_{\text{max}}$  measured at 250 and 10 kHz), which was determined from the dielectric curves for all the compositions. It is observed that  $\Delta T_{\text{max}}$  generally increases with the content of x, which is another indication that BT–BI ceramics transition to a relaxor state as x increases. Data for  $T_{\text{max}}$ , relative permittivity and tan  $\delta$  for compositions 0.03 < x < 0.12 are listed in Table 2.

# Ferroelectric hysteresis

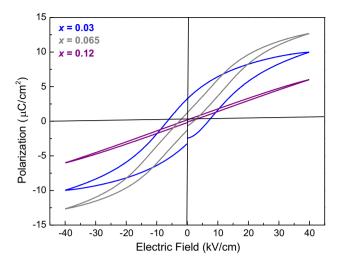
Ferroelectric P–E hysteresis loop measurements were taken at room temperature under an applied electric field of 40 kV/cm at 0.1 Hz for all compositions as shown in Fig. 6 and Fig. S11. At x=0.03, the polarization loop resembles that of the ferroelectric parent compound BT. This composition shows a nearly saturated loop with a remnant polarization ( $P_r$ ) of 3.25  $\mu$ C/cm². As the amount of BI increases to x=0.075,  $P_r$  decreases while still showing hysteresis, indicating the presence of nano-sized polar domains and a transition to a relaxor ferroelectric. This agrees

**Table 2** Dielectric permittivity data for (1 - x)BT-(x)BI ceramics

Composition $(x)$	$T_{\rm max}$ (°C)	Relative permittivity at $T_{\rm max}$	Room temperature		$\Delta T_{\rm max}$
			Relative permittivity	$ an\delta$	(°C)
0.03	133	1549	950	0.031	~0.5
0.05	118	1730	870	0.028	2
0.06	110	1960	1056	0.027	5
0.065	45	3220	3100	0.07	13
0.075	37	2500	2480	0.06	21
0.1	47	1720	1687	0.05	25
0.12	62	1489	1430	0.062	30

Data obtained from 10 kHz measurement.  $\Delta T_{\rm max}$  is the difference between  $T_{\rm max}$  measured at 250 and 10 kHz





**Fig. 6** Room temperature P-E hysteresis loops measured at 0.1 Hz for (1 - x)BT-(x)BI ceramics for x = 0.03 (blue), x = 0.065 (gray) and x = 0.12 (purple).

well with the dielectric permittivity data. For compositions x = 0.10, 0.12, the P–E loops are nearly linear, showing hysteresis, but no saturation of dipoles. While these compositions still show relaxor behavior, this could be due to the size of the nanodomains or presence of increasing non-polar cubic  $Pm\bar{3}m$  phase as determined by the Rietveld refinements.

The maximum polarization ( $P_{\rm max}$ ) is achieved for composition x=0.065 with a value of  $12.6~\mu \rm C/cm^2$  and is referred to as the critical composition. This data is also consistent with the dielectric results obtained where the maximum value for the relative permittivity is also at x=0.065. This enhancement of dielectric and ferroelectric properties at the critical composition can be attributed to a phase transformation from a ferroelectric to a relaxor phase. This phenomenon has been previously observed in other systems such as:  $(Bi_{0.5}Na_{0.41}K_{0.09})_{1-x}La_xTiO_3$  where

**Table 3** Maximum polarization  $(P_{\text{max}})$  and remnant polarization  $(P_{\text{r}})$  from P-E measurements

 $P_{\rm max}~(\mu{\rm C/cm}^2)$ Composition (x) $P_r (\mu \text{C/cm}^2)$ Strain (%)  $d_{33}^* \text{ (pm/V)}$ h (%) 9.96 0.03 17 3.25 0.048 120 9.23 2.4 17 0.05 0.046 115 0.06 9.75 3.06 0.059 147 26 0.065 12.64 1.21 0.104 260 11 150 11 0.075 11.13 0.55 0.06 0.4 78 0.1 7.65 0.031 11 25 0.12 5.98 0.19

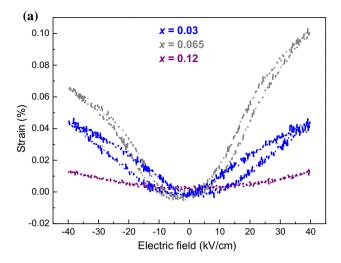
Strain from unipolar S-E field loops, effective piezoelectric coefficient  $d_{33}^* (= S_{\text{max}}/E_{\text{max}})$ , where  $S_{\text{max}}$  is the strain observed at the maximum field  $E_{\text{max}}$ ) and finite hysteresis h (= $\Delta S/S_{\text{max}}$ ; where  $\Delta S$  is the width of the widest part of the loop)

the value of  $P_{\rm max}$  is about  $40~\mu{\rm C/cm}^2$  at the critical composition x=0.03 [36] and for  $(0.94-x)({\rm Na}_{0.5}{\rm Bi}_{0.5}){\rm TiO}_3$ -0.06BaTiO<sub>3</sub>- $x{\rm Bi}({\rm Me}_{0.5}{\rm Ti}_{0.5}){\rm O}_3$  (Me = Zn (Z), Ni (N), Mg(M), Co(C)) (NBT-BT-B(Me<sub>0.5</sub>Ti<sub>0.5</sub>)O<sub>3</sub> with  $P_{\rm max}$  values ranging between 35 and 40  $\mu{\rm C/cm}^2$  at the critical compositions for 0.0275BZT, 0.03BMT, 0.035BNiT and 0.04BCT [37, 38]. The  $P_{\rm max}$  values of other related systems are 14  $\mu{\rm C/cm}^2$  for the relaxor 0.95BT-0.05BA [32] and 40  $\mu{\rm C/cm}^2$  for the ferroelectric 0.64PT-0.36BS [35]. Values for  $P_{\rm max}$  and  $P_{\rm r}$  are listed in Table 3.

# Piezoelectric properties

The electromechanical strain was investigated at room temperature with a measurement frequency of 0.1 Hz and an applied electric field of 40 kV/cm. Figure 7a shows the bipolar strain-electric field loops for compositions x = 0.03, 0.065 and 0.12. For the compositions in the range  $0.03 \le x \le 0.075$ , the bipolar strain exhibits the classic butterfly loop which indicates bulk piezoelectricity. These compositions also show evidence of ferroelectric switching in their negative strain component. However, for x > 0.10, the butterfly loops disappear and transform to parabolic curves with negligible hysteresis and no negative strain component as shown in Fig. 7a and Fig. S12a. The decrease and eventual elimination of the negative strain component as x increases indicates an increase in the ergodic behavior of the relaxor ferroelectric [39]. When the transition occurs from ferroelectric to relaxor ferroelectric, the continued presence of negative strain indicates that some of the polar nanoregions are frozen and the application of an external field during the S-E measurement causes ferroelectric switching. Eventually, at x = 0.10, the negative strain component disappears due to the fluctuation of dipoles and no switching





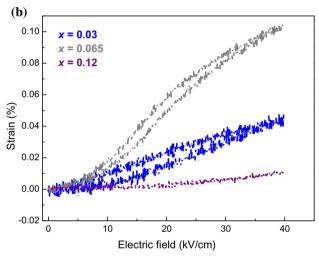


Fig. 7 For (1 - x)BT-(x)BI ceramics room temperature: a bipolar and b monopolar strain-electric field measurements performed at 0.1 Hz for x = 0.03 (blue), x = 0.065 (gray) and x = 0.12 (purple).

occurs. The results of the *S–E* measurements are in good agreement with both the *P–E* loops and permittivity measurements. The strain response of the studied material under unipolar *E* cycling was measured to investigate its potential for actuators applications, Fig. 7b and Fig. S12b. The highest strain value achieved is by the critical composition x = 0.065 with a value of 0.104%, which is higher than that of 0.95BT–0.05BA (0.07%) [32] but lower than 0.64PT–0.36BS (0.17%) [35], (Bi<sub>0.5</sub>Na<sub>0.41</sub>K<sub>0.09</sub>)<sub>0.97</sub>La<sub>0.03</sub>TiO<sub>3</sub> (0.35%) [36] and the critical compositions specified before for the NBT-BT-B(Me<sub>0.5</sub>Ti<sub>0.5</sub>)O<sub>3</sub> system (0.35–0.40%) [37, 38]. This result is consistent with the dielectric and *P–E* loops measurements where the highest values of the relative permittivity and  $P_{\text{max}}$  also come from x = 0.065 as

Fig. 8 and Table 3 show. All the unipolar loops exhibit nonlinearity with finite hysteresis (h) values (Table 3). The composition x = 0.065 in particular exhibits a high nonlinear-strain-electric field behavior. The nonlinearity could be due to extrinsic effects (as opposed to intrinsic effects or lattice response) that arise mainly from domain wall motion, although additional contributions can occur, such as grain boundary effects and displacement of inter-phase boundaries [2, 40, 41]. As shows, for the P4mm + R3m region,  $0.03 \le x \le 0.75$ ,  $d_{33}^*$  increases sharply for the critical composition x = 0.065 with a value of 260 pm/V. However, as expected for the  $Pm\bar{3}m + R3m$  region, x > 0.10,  $d_{33}^{*}$  decreases with x being 25 pm/V for x = 0.12. This agrees well with the linear P–E loops and  $P_{\rm r}$  decreasing to nearly zero in this region. For comparison, for the NBT-BT-B(Me<sub>0.5</sub>Ti<sub>0.5</sub>)O<sub>3</sub> system  $d_{33}^{*}$  values at the critical compositions range between 550 and 600 pm/V. Moreover, for the critical composition x = 0.065, a significant reduction in the  $P_r$  can be clearly observed (Fig. 8b), resulting in a relaxor-like P-E loop (Fig. 6) possibly due to the coexistence of ferroelectric and relaxor phases [36, 38]. This behavior has been observed in the similar systems NBT-BT- $B(Me_{0.5}Ti_{0.5})O_3$  and  $(Bi_{0.5}Na_{0.41}K_{0.09})_{1-x}La_xTiO_3$  where the  $P_{\rm r}$  is decreased and  $d_{33}^*$  enhanced for the critical compositions. Piezoresponse force microscopy studies have shown that for  $(Bi_{0.5}Na_{0.41}K_{0.09})_{0.97}La_{0.03}TiO_3$  the giant strain response ( $d_{33}^* = 857 \text{ pm/V}$ ) was accompanied by the nanoscale coexistence of ferroelectric and relaxor phases [36]. Values for strain,  $d_{33}^*$  and h for (1 - x)BT-(x)BI ceramics are collected in Table 3.

In this study, on the basis of the structural analysis, dielectric, ferroelectric and piezoelectric properties discussed above, a phase diagram for the system (1 - x)BT-(x)BI was established as Fig. 9 shows. In addition, above each composition range the corresponding structures are displayed. We can observe that  $T_{\text{max}}$  decreases with BI content linearly in the range  $0.03 \le x \le 0.06$ . However, at the critical composition x = 0.065, where the large strain response is observed,  $T_{\text{max}}$  decreases sharply increasing slightly again when  $x \ge 0.10$  at the multi-phase region  $Pm\bar{3}m + R\bar{3}m$ . Therefore, from the measured electrical properties, we concluded that the large strain response at x = 0.065 is closely associated with the composition and temperature-induced phase transformation leading to the coexistence of ferroelectric and relaxor phases.



Fig. 8 *a* Variation of the effective piezoelectric coefficient  $(d_{33}^*)$  calculated from monopolar S–E loops. b Remnant polarization  $(P_r)$  and c relative permittivity  $(\varepsilon)$  with BI content (x). The gray dashed line indicates approximate the region where a change in symmetry takes place from P4mm + R3m to  $Pm\bar{3}m + R3m$ , while the dark red shadow area indicates the critical composition x = 0.065.

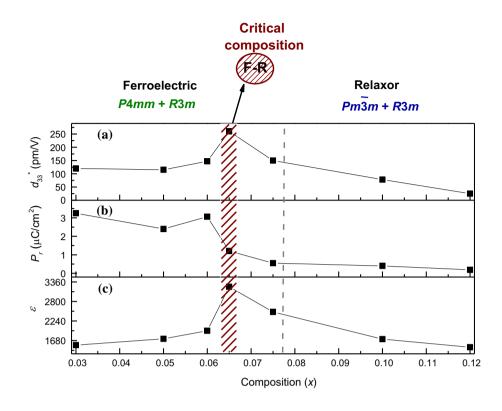
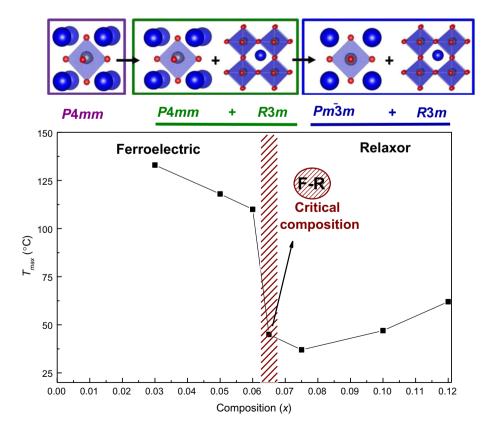


Fig. 9 Schematic phase diagram for the (1 - x)BT - (x)BI ceramics. The  $T_{max}$  values are those from Table 2 and were taken from the 10 kHz permittivity data.





# Morphotropic phase boundary and polarization extension

While an enhanced piezoelectric response is evident at x = 0.065, we do not consider this system to have an MPB but a critical composition with a mixture of ferroelectric and relaxor phases as in the systems NBT-BT- $B(Me_{0.5}Ti_{0.5})O_3$  and  $(Bi_{0.5}Na_{0.41}K_{0.09})_{1-x}La_xTiO_3$  [36–38]. As the amount of BI is added to the system, the material transitions from a traditional ferroelectric material as the parent BT to a relaxor ferroelectric. The structural transition is not a sharp sudden transition, rather the percent of the pseudo-cubic rhombohedral phase slowly increases in the range  $0.03 \le x \le 0.075$  and the frequency dependence of  $T_{\text{max}}$  in the permittivity measurements becomes broader as a function of x. This is similar to the systems BT-BA [32] and BT-BS [28]. Alternatively, when these same phases are used in solid solutions with PT as in PT-BI [20] PT-BS [19, 34, 35] and PT-BA [33], the ferroelectric phases remains over a large composition range and in PT-BS [19, 34, 35], an MPB between two ferroelectric phases forms. Solid solutions of Bi-based perovskites with BT likely lead to relaxor ferroelectrics due to the formation of polar nanodomains resulting from competition on the A-site where Ba<sup>2+</sup> prefers a more symmetric coordination environment and Bi<sup>3+</sup> prefers a distorted coordination environment due to the lone pair effect. Alternatively when Bi-based compounds are used with PT, the tetragonality is reduced, but the system maintains its ferroelectric properties as the structure changes because both cations cause distortions from the presence of a lone pair, eliminating the instability caused by the different A-site cations.

As this system is not considered to have a morphotropic phase boundary, it does not have a polarization extension mechanism as predicted [8, 10]. As mentioned above, compositions where  $x \ge 0.10$  are multi-phase and contain the cubic  $Pm\bar{3}m$  and rhombohedral R3m structures, not single phase cubic as reported by Datta. While this particular material does not meet the criteria for a material with a polarization extension, we believe that it is important to continue the search for these nontraditional piezoelectrics.

#### **Conclusions**

With the introduction of BI into BT, a gradual phase transition from a polar tetragonal structure to a multiphase tetragonal and rhombohedral structure to a multi-phase pseudo-cubic structure was observed. As the content of BI increases, a ferroelectric to relaxor ferroelectric transition occurs as the frequency dependence broadens and  $T_{\rm max}$  decreases. The relative permittivity, maximum polarization and effective piezoelectric coefficient are maximized for the critical composition x=0.065 as a result of the coexistence of ferroelectric and relaxor phases with a strain value of  $\sim 0.104\%$  and a  $d_{33}^*$  of 260 pm/V under a moderate electric field of 40 kV/cm.

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# Compliance with ethical standards

**Conflicts of interest** The authors declare that they have no conflicts of interest regarding this work.

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